# S2A THRU S2M

# SURFACE MOUNT GLASS PASSIVATED SILICON RECTIFIER

# REVERSE VOLTAGE: FORWARD CURRENT:

50 to 1000 VOLTS 2.0 AMPERE

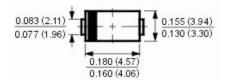
## FEATURES

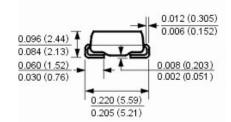
- · Plastic package has Underwriters Laboratory
- Flammability Classification 94V-O
- $\cdot$  For surface mounted applications
- $\cdot$  Low profile package
- $\cdot$  Easy pick and place
- · Built-in strain relief
- $\cdot$  Low forward voltage drop
- $\cdot$  High temperature soldering : 250°C /10 seconds at terminals

#### MECHANICAL DATA

Case: Molded plastic, DO-214AA(SMB) Terminals: Solder plated, solderable per MIL-STD-750, method 2026 guaranteed Polarity: Color band denotes cathode end Packaging: 12mm tape per EIA STD RS-481 Weight: 0.003 ounce, 0.093 gram

### DO-214AA(SMB)





Dimensions in inches and (millimeters)

## Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave,  $60H_Z$ , resistive or inductive load. For capacitive load, derate current by 20%.

	Symbols	S2A	S2B	S2D	S2G	S2J	S2K	S2M	Units
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at T <sub>L</sub> =90°C	I <sub>(AV)</sub>	2.0							Amp
Peak Forward Surge Current,									
8.3ms single half-sine-wave	I <sub>FSM</sub> 50								Amp
superimposed on rated load (JEDEC method)									
Maximum Forward Voltage at 2.0A	V <sub>F</sub>	1.15							Volts
Maximum Reverse Current at T <sub>A</sub> =25°C	I <sub>R</sub>	5.0 125							μАтр
at Rated DC Blocking Voltage T <sub>A</sub> =125°C	IR								
Typical Junction Capacitance (Note 1)	CJ	30							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JL}$	16							°C/W
Maximum Reverse Recovery Time (Note 3)	T <sub>RR</sub>	2.5							μS
Operating Junction Temperature Range	T <sub>J</sub>	-55 to +150							Ĉ
Storage Temperature Range	Tstg	-55 to +150							Ĉ

#### NOTES:

1- Measured at 1  $\ensuremath{\text{MH}}_{\ensuremath{\text{Z}}}$  and applied reverse voltage of 4.0 VDC.

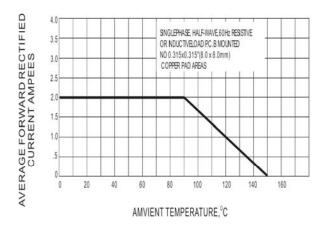
2- Thermal resistance from junction to lead mounted on P.C.B. with 0.3 x 0.3" (8.0 x 8.0mm) copper pad areas

3- Reverse Recovery Test Conditions:  $I_F$ =.5A,  $I_R$ =1A,  $I_{RR}$ =.25A.

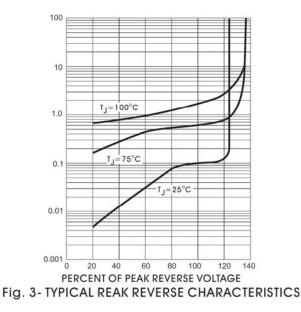


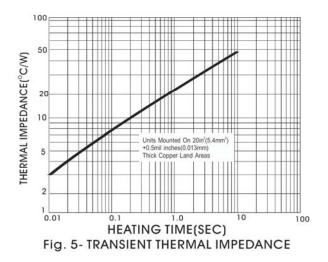


# RATINGS AND CHARACTERISTIC CURVES









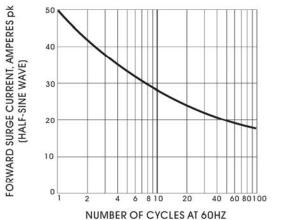
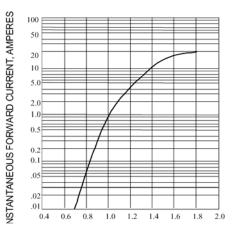


Fig.2-MAXIMUM OVERLOAD SURGE-CURRENT



INSTANTANEOUS FORWARD VOLTAGE, VOLTS

Fig. 4-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

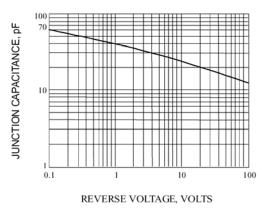


Fig. 6-TYPICAL JUNCTION CAPACITANCE